|    | Type | Hits  | Search Text   | DBs  | Time Stamp          |
|----|------|-------|---|--|---------------------|
| ŧ  | IS&R | 8710  | (257/698,752,758,773-776,781,786).CCLS.   | USPAT  | 2008/09/01<br>08:53 |
| 2  | IS&R | 5935  | (257/698,752,758,773-776,781,786).CCLS.   | US-PGPUB;<br>USOCR;<br>FPRS; EPO;<br>JPO;<br>DERWENT;<br>IBM_TDB | 2608/09/01<br>08:53 |
| 3  | IS&R | 7457  | (438/612,614,618,622,629,637,639,640,666,6<br>68,672).CCLS.   | USPAT  | 2008/09/01<br>08:56 |
| 4  | IS&R | 7279  | (438/612,614,618,622,629,637,639,640,666,6<br>68,672).CCLS.   | US-PGPUB;<br>USOCR;<br>FPRS; BPO;<br>JPO;<br>DERWENT;<br>IBM_TDB | 2008/09/01<br>08:58 |
| s  | BRS  | 1648  | (active transistor gate) and ((bond bonding)<br>near2 (pad)) and ((frame framed) near3 (wire<br>wiring interconnect interconnection layer<br>film)) | USPAT  | 2008/09/01<br>09:00 |
| 6  | BRS  | 150   | near2 (pad)) and ((frame framed) near3 (wire<br>wiring interconnect interconnection layer<br>film))   | US-PGPUB;<br>USOCR;<br>FPRS; EPO:<br>JPO;<br>DERWENT;<br>IBM_TDB | 2008/09/01<br>09:01 |
| 7  | IS&R | 1728  | (257/E23.02,E23.152,E23.194).CCLS.  | USPAT  | 2008/09/02<br>17:32 |
| 8  | is&r | 15424 | ((257/698,752,758,773-776,781,786) or<br>(438/612,614,618,622,629,637,639,640,666,6<br>68,672)).CCLS.   | USPAT  | 2008/09/02<br>17:32 |
| 9  | BRS  | 752   | \$60 pat \$61   | USPAT  | 2008/09/02<br>17:32 |
| 10 | IS&R | 12380 | ((257/698,752,758,773-776,781,786) or<br>(438/612,614,618,622,629,637,639,640,666,6<br>68,672)).CCLS.   | US-PGPUB;<br>USOCR;<br>IPRS; EPO;<br>IPO;<br>DERWENT;<br>IBM TDB | 2008/09/02<br>17:33 |

|    | Type | Hits | Search Text   | DBs  | Time Stamp          |
|----|------|------|---|--|---------------------|
| į  | S&R  | 1770 | (257/E23.02,E23.152,E23.194).CCLS.  | US-PGPUB;<br>USOCR;<br>FPRS; EPO;<br>JPO;<br>DERWENT;<br>IBM_TDB | 2008/09/02<br>17:34 |
| 12 | BRS  | 1251 | \$64 not \$63   | US-PGPUB;<br>USOCR;<br>FPRS; EPO;<br>JPO;<br>DERWENT;<br>IBM_TDB | 2008/09/02<br>17:34 |
| 3  | BRS  | 48   | ((active transistor gate) and ((bond bonding) near2 (pad)) and ((frame framed) near3 (wire wiring interconnect interconnection layer film))).clm.                                   | US-PGPUB   | 2008/09/02<br>20:00 |
| 14 | BRS  | U    | ((active transistor gate) and ((bond bonding) uear2 (pad)) and ((frame framed) near3 (wire wiring interconnect interconnection layer (film)) and (bus) and (opening via hole)).clm. | USPAT  | 2008/09/03<br>08:23 |
| Š  | BRS  | 13   | ((active transistor gate) and ((bond bonding) near2 (pad)) and ((frame framed) near3 (wire wiring interconnect interconnection layer film)) and (opening via hole)).clm.            | USPAT  | 2008/09/03<br>08:29 |